# imall

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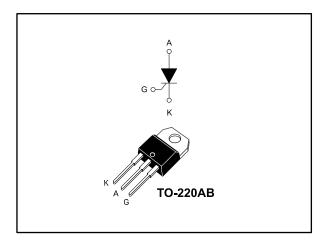
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## High temperature 40 A SCRs

Datasheet - production data



### Features

- High junction temperature: T<sub>j</sub> = 150 °C
- High noise immunity dV/dt = 500 V/µs up to 150 °C
- Gate triggering current IGT = 15 mA
- Peak off-sate voltage 600 V VDRM/VRRM
- High turn on current rise dl/dt = 100 A/µs
- ECOPACK<sup>®</sup>2 compliant component
- Insulated package TO-220AB:
  Insulated voltage: 2500 V<sub>RMS</sub>
- Complies with UL 1557 (File ref : E81734)

This is information on a product in full production.

### **Applications**

- Motorbike voltage regulator circuits
- Inrush current limiting circuit
- Motor control circuits and starters
- Solid state relays

### Description

Thanks to its junction temperature  $T_j$  up to 150 °C, the device offers high thermal performances operation up to 40 Å. It is fully tab insulated thanks to the ceramic inside the TO-220AB package and allows a back to back configuration.

Its trade-off noise immunity (dV/dt =  $500 \text{ V/}\mu\text{s}$ ) versus its gate triggering current (I<sub>GT</sub> = 15 mA) and its turn-on current rise (dI/dt =  $100 \text{ A/}\mu\text{s}$ ) allows to design robust and compact control circuit for voltage regulator in motorbikes and industrial drives, overvoltage crowbar protection, motor control circuits in power tools and kitchen aids, inrush current limiting circuits.

### Table 1: Device summary

Order code	Package	$V_{DRM}/V_{RRM}$	IGT	
TN4015H-6I	TO-220AB ins.	600 V	15 mA	

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#### 1 **Characteristics**

Table 2: Absolute maximum ratings (limiting values), T	T <sub>j</sub> = 25 °C unless otherwise specified
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Symbol	Para	meter		Value	Unit	
I <sub>T(RMS)</sub>	RMS on-state current (180 ° conduction angle)	T <sub>c</sub> = 82 °C	40	А		
	<b>.</b>		T <sub>c</sub> = 83 °C	25		
I <sub>T(AV)</sub>	Average on-state current (180 ° conduction angle)		$T_c = 94 \ ^\circ C$	22	А	
			T <sub>c</sub> = 101 °C	20		
	Non repetitive ourge peak on a	toto ourropt	t <sub>p</sub> = 8.3 ms	394		
Ітѕм	Non repetitive surge peak on-s	state current	t <sub>p</sub> = 10 ms	360	A	
l <sup>2</sup> t	I <sup>2</sup> t value for fusing		t <sub>p</sub> = 10 ms	648	A <sup>2</sup> s	
dl/dt	Critical rate of rise of on-state current		f = 60 Hz	100	A/µs	
	l <sub>G</sub> = 2 x l <sub>GT</sub> , tr ≤ 100 ns		1 - 00 112	100	7.0μ0	
VDRM/VRRM	Repetitive peak off-state voltage	ge	T <sub>j</sub> = 150 °C	600	V	
V <sub>DSM</sub> /V <sub>RSM</sub>	Non repetitive surge peak off-s	t <sub>p</sub> = 10 ms	V <sub>DRM</sub> /V <sub>RRM</sub> + 100	V		
Ідм	Peak gate current	$t_p = 20 \ \mu s$	$T_j = 150 \ ^\circ C$	4	А	
P <sub>G(AV)</sub>	Average gate power dissipatio	1	W			
VRGM	Maximum peak reverse gate v	5	V			
T <sub>stg</sub>	Storage junction temperature r	-40 to +150	°C			
Tj	Maximum operating junction te	-40 to +150	°C			
TL	Maximum lead temperature so	Idering during 10	)s	260	°C	

### Table 3: Electrical characteristics (T<sub>j</sub> = 25 °C unless otherwise specified)

Symbol	Test Conditions		Value	Unit	
I <sub>GT</sub>			Max.	15	mA
Vgt	$V_{D} = 12 V, R_{L} = 33 \Omega$		Max.	1.3	V
Vgd	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$	T <sub>j</sub> = 150 °C	Min.	0.15	V
Ін	I⊤ = 500 mA, gate open	Max.	60	mA	
١L	$I_G = 1.2 \text{ x } I_{GT}$	Max.	80	mA	
dV/dt	$V_D = 402 \text{ V}$ , gate open $T_j = 150 \text{ °C}$		Min.	500	V/µs
t <sub>gt</sub>	$I_T = 80 \text{ A}, V_D = 600 \text{ V}, I_G = 100 \text{ mA}, (dI_G/dt) \text{ max}$	Тур.	1.9	μs	
tq	$V_D = 402 \text{ V}, I_T = 40 \text{ A}, V_R = 25 \text{ V},$ $dV_D/dt = 50 \text{ V}/\mu \text{s}, (dI_G/dt) \text{ max} = 30 \text{ A}/\mu \text{s}$	T <sub>j</sub> = 150 °C	Тур.	85	μs

### Characteristics

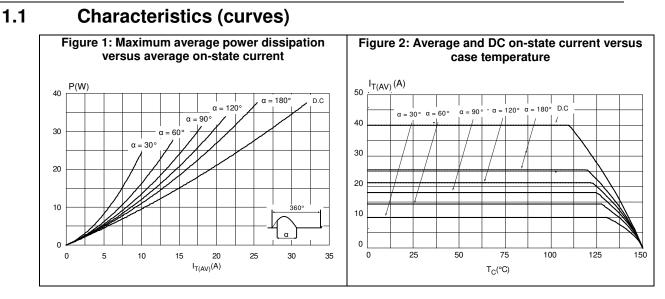
Table 4: Static characteristics						
Symbol	Test conditions Value Unit				Unit	
Vtm	$I_{TM} = 80 \text{ A}, t_p = 380 \ \mu s$	$T_j = 25 \ ^\circ C$	Max.	1.6	V	
V <sub>TO</sub>	Threshold voltage	$T_j = 150 \ ^\circ C$	Max.	0.85	v	
RD	Dynamic resistance	T <sub>j</sub> = 150 °C	Max.	10	mΩ	
Idrm, Irrm		T <sub>j</sub> = 25 °C	Max	10	μA	
	V <sub>D</sub> = V <sub>DRM</sub> = V <sub>RRM</sub>	T <sub>j</sub> = 150 °C	Max.	6	mA	

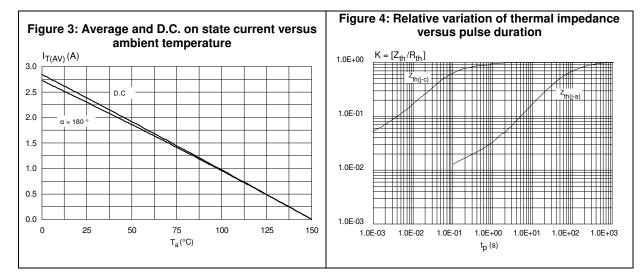
### Table 5: Thermal parameters

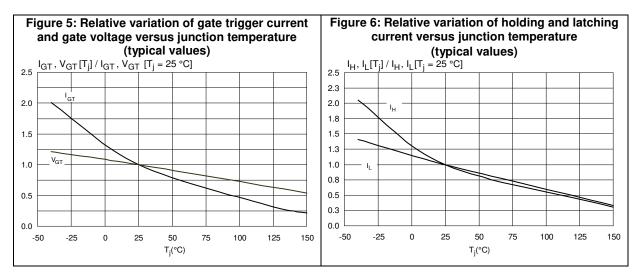
Symbol	Parameter	Value	Unit	
Rth(j-c)	Junction to case (DC)		1.8	00 AM
R <sub>th(j-a)</sub>	Junction to ambient (DC)		60	°C/W



Characteristics





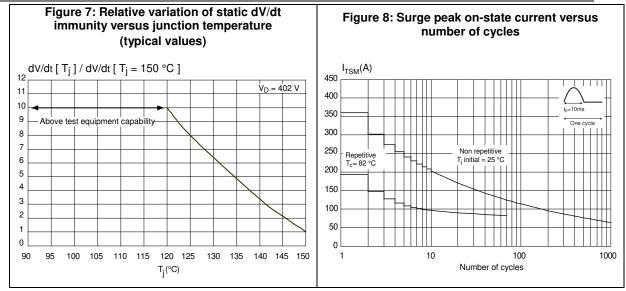


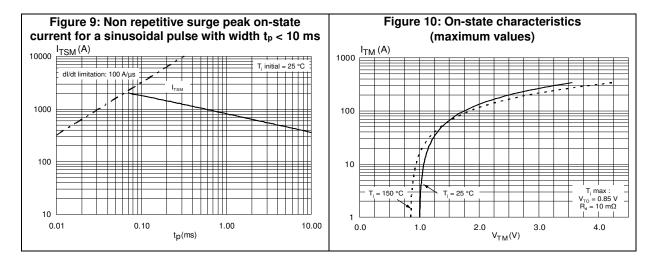
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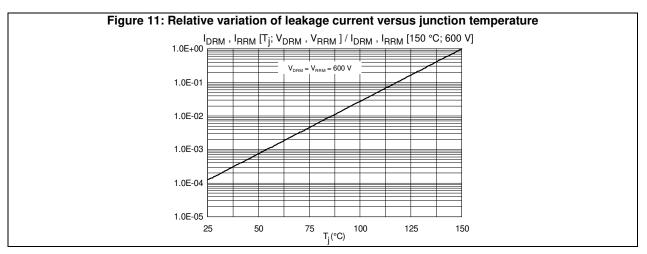


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Characteristics







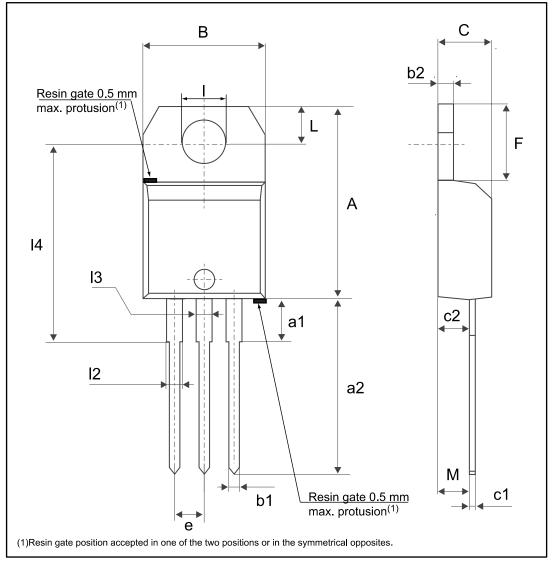
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### 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.

- Epoxy meets UL94, V0
- Lead-free, halogen-free package

### 2.1 TO-220AB insulated package information



#### Figure 12: TO-220AB insulated package outline

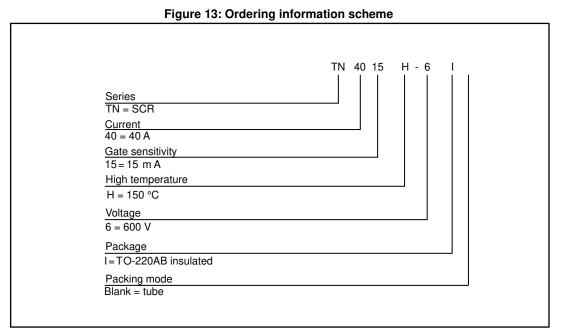




I	Package information					
	Tal	ole 6: TO-220/	AB insulated p	oackage mecha	nical data	
			Dir	nensions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
В	10.00		10.4	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
С	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
е	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
ØI	3.73		3.88	0.1469		0.1528
14	15.80	16.40	16.8	0.6220	0.6457	0.6614
L	2.65		2.95	0.1043		0.1161
12	1.14		1.70	0.0449		0.0669
13	1.14		1.70	0.0449		0.0669
М		2.60			0.1024	



### **3** Ordering information



#### Table 7: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TN4015H-6I	TN4015H6I	TO-220AB Ins.	2.3 g	50	Tube

### 4 Revision history

#### Table 8: Document revision history

Date	Revision	Changes
05-Oct-2016	1	Initial release.
25-Nov-2016	2	Updated cover image.

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